



IXTP08N100P Information

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For Reference Only

Part Number IXTP08N100P

Manufacturer IXYS

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 1000V 800MA TO-220

Package TO-220-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IXTP08N100P Specifications

Manufacturer Part Number	IXTP08N100P
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	Polar?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	1000V
Current - Continuous Drain (Id) @ 25°C	800mA (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 50μA
Gate Charge (Qg) (Max) @ Vgs	11.3nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	240pF @ 25V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	42W (Tc)
Rds On (Max) @ Id, Vgs	20 Ohm @ 500mA, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220AB
Package / Case	TO-220-3
	Report errors?

IXTP08N100P Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IXTP08N100P Payment Methods



















IXTP08N100P Shipping Methods













If you have any question about IXTP08N100P, please do not hesitate to contact us!

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